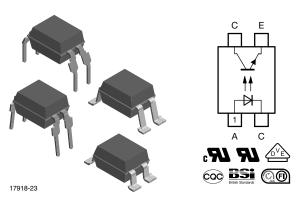


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# **Optocoupler, Phototransistor Output, High Temperature**



### **DESCRIPTION**

The VO615A consists of a phototransistor optically coupled to a gallium arsenide infrared-emitting diode in a 4 pin plastic dual inline package.

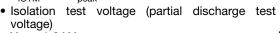
### **AGENCY APPROVALS**

(All parts are certified under base model VO615A)

- BSI: EN 60065:2002, EN 60950-1:2006
- DIN EN 60747-5-5 (VDE 0884), available with option 1
- FIMKO: FI25155
- UL 1577 file no. E52744
- cUL 1577 tested to CSA 22.2 bulletin 5A
- CQC file no. 09001038077; 09001038080

#### **FEATURES**

- Temperature range 55 °C to + 110 °C
- Rated impulse voltage (transient overvoltage)
   V<sub>IOTM</sub> = 6 kV<sub>peak</sub>



 $V_{pd} = 1.6 \text{ kV}$ 

(e3) **RoHS** 

- Rated isolation voltage (RMS includes DC)
   V<sub>IOWM</sub> = 600 V<sub>RMS</sub>
- Rated recurring peak voltage (repetitive) V<sub>IORM</sub> = 850 V<sub>peak</sub>
- Material categorization: For definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### **APPLICATIONS**

Circuits for safe protective separation against electrical shock according to safety class II (reinforced isolation):

- Application class I to IV at mains voltage ≤ 300 V
- Application class I to IV at mains voltage ≤ 600 V according to table 1 of IEC 60664-1, suitable for:
  - Switch-mode power supplies
  - Line receiver
  - Computer peripheral interface
  - Microprocessor system interface

| ORDERING INFO                       | RMATIC   | N                 |                   |                   |                   |                   |                   |                   |                   |                   |
|-------------------------------------|--|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|
| V 0 6                               | 1  | 5 A               | -                 | # X               | 0                 | #                 | # Т               | DIP-#             | Option 6          | Option 7          |
| PAF                                 | PART NUMBER CTR PACKAGE OPTION TAPE BIN AND REEL 9,9,27 mm 1 7 > 0.6 m |                   |                   |                   |                   |                   |                   |                   |                   |                   |
| AGENCY CERTIFIED/                   |  |                   |                   |                   | СТЕ               | ર (%)             |                   |                   |                   |                   |
| PACKAGE                             | 5 mA   |                   | 10                | mA                |                   |                   |                   | 5 mA              |                   |                   |
| BSI, FIMKO, UL, cUL, CQC (option 1) | 50 to 600  | 40 to 80          | 63 to 125         | 100 to 200        | 160 to 320        | 50 to 150         | 100 to 300        | 80 to 160         | 130 to 260        | 200 to 400        |
| DIP-4                               | VO615A   | VO615A-1          | VO615A-2          | VO615A-3          | VO615A-4          | VO615A-5          | VO615A-6          | VO615A-7          | VO615A-8          | VO615A-9          |
| DIP-4, 400 mil,<br>option 6         | VO615A-<br>X006  | VO615A-<br>1X006  | VO615A-<br>2X006  | VO615A-<br>3X006  | VO615A-<br>4X006  | VO615A-<br>5X006  | VO615A-<br>6X006  | VO615A-<br>7X006  | VO615A-<br>8X006  | VO615A-<br>9X006  |
| SMD-4, option 7                     | VO615A-<br>X007T   | VO615A-<br>1X007T | VO615A-<br>2X007T | VO615A-<br>3X007T | VO615A-<br>4X007T | VO615A-<br>5X007T | VO615A-<br>6X007T | VO615A-<br>7X007T | VO615A-<br>8X007T | VO615A-<br>9X007T |
| SMD-4, option 8                     | -  | -                 | -                 | VO615A-<br>3X008T | -                 | -                 | -                 | -                 | -                 | -                 |
| SMD-4, option 9                     | VO615A-<br>X009T   | VO615A-<br>1X009T | VO615A-<br>2X009T | VO615A-<br>3X009T | VO615A-<br>4X009T | VO615A-<br>5X009T | VO615A-<br>6X009T | VO615A-<br>7X009T | -                 | -                 |
| VDE, BSI, FIMKO, UL, cUL, CQC       | 50 to 600  | 40 to 80          | 63 to 125         | 100 to 200        | 160 to 320        | 50 to 150         | 100 to 300        | 80 to 160         | 130 to 260        | 200 to 400        |
| DIP-4                               | VO615A-<br>X001  | VO615A-<br>1X001  | VO615A-<br>2X001  | VO615A-<br>3X001  | VO615A-<br>4X001  | -                 | VO615A-<br>6X001  | VO615A-<br>7X001  | VO615A-<br>8X001  | -                 |
| DIP-4, 400 mil,<br>option 6         | -  | -                 | VO615A-<br>2X016  | VO615A-<br>3X016  | VO615A-<br>4X016  | VO615A-<br>5X016  | -                 | -                 | VO615A-<br>8X016  | VO615A-<br>9X016  |
| SMD-4, option 7                     | VO615A-<br>X017T   | VO615A-<br>1X017T | -                 | VO615A-<br>3X017T | VO615A-<br>4X017T | -                 | VO615A-<br>6X017T | VO615A-<br>7X017T | VO615A-<br>8X017T | VO615A-<br>9X017T |
| SMD-4, option 8                     | -  | -                 | -                 | VO615A-<br>3X018T | VO615A-<br>4X018T | -                 | i                 | -                 | VO615A-<br>8X018T |                   |
| SMD-4, option 9                     | -  | VO615A-<br>1X019T | VO615A-<br>2X019T | VO615A-<br>3X019T | VO615A-<br>4X019T | -                 | -                 | -                 | -                 | -                 |

#### Note

• Additional options may be possible, please contact sales office.



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| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                                      |                   |  |                  |  |  |
|--|--------------------------------------|-------------------|--|------------------|--|--|
| PARAMETER  | TEST CONDITION                       | SYMBOL            | VALUE  | UNIT             |  |  |
| INPUT  |                                      |                   |  |                  |  |  |
| Reverse voltage  |                                      | $V_{R}$           | 6  | V                |  |  |
| Forward current  |                                      | I <sub>F</sub>    | 60   | mA               |  |  |
| Forward surge current  | t <sub>p</sub> ≤ 10 μs               | I <sub>FSM</sub>  | 1.5  | Α                |  |  |
| LED power dissipation  | at 25 °C                             | P <sub>diss</sub> | 70   | mW               |  |  |
| OUTPUT   |                                      |                   | <u>.                                      </u> |                  |  |  |
| Collector emitter voltage  |                                      | $V_{CEO}$         | 70   | V                |  |  |
| Emitter collector voltage  |                                      | V <sub>ECO</sub>  | 7  | V                |  |  |
| Collector current  |                                      | I <sub>C</sub>    | 50   | mA               |  |  |
| Collector peak current   | $t_p/T = 0.5, t_p \le 10 \text{ ms}$ | I <sub>CM</sub>   | 100  | mA               |  |  |
| Output power dissipation   | at 25 °C                             | P <sub>diss</sub> | 70   | mW               |  |  |
| COUPLER  |                                      |                   | <u>.                                      </u> |                  |  |  |
| Isolation test voltage (RMS)   | t = 1 s                              | V <sub>ISO</sub>  | 5000   | V <sub>RMS</sub> |  |  |
| Operating ambient temperature range  |                                      | T <sub>amb</sub>  | - 55 to + 110                                  | °C               |  |  |
| Storage temperature range  |                                      | T <sub>stg</sub>  | - 55 to + 125                                  | °C               |  |  |
| Soldering temperature (1)  | 2 mm from case, ≤ 10 s               | T <sub>sld</sub>  | 260  | °C               |  |  |

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD), and wave profile for soldering conditions for through hole devices (DIP), please go to "Assembly Instructions" (<a href="www.vishay.com/doc?80054">www.vishay.com/doc?80054</a>).

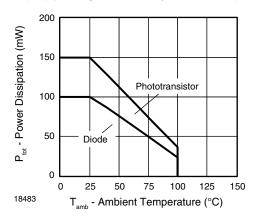


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature

| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                    |      |      |      |      |  |
|--|---|--------------------|------|------|------|------|--|
| PARAMETER  | TEST CONDITION  | SYMBOL             | MIN. | TYP. | MAX. | UNIT |  |
| INPUT  |   |                    |      |      |      |      |  |
| Forward voltage  | I <sub>F</sub> = 50 mA  | $V_{F}$            |      | 1.43 | 1.6  | V    |  |
| Reverse current  | V <sub>R</sub> = 6 V  | $I_R$              |      |      | 100  | μΑ   |  |
| Junction capacitance   | $V_R = 0$ , $f = 1 MHz$   | Cj                 |      | 50   |      | pF   |  |
| OUTPUT   |   |                    |      |      |      |      |  |
| Collector emitter voltage  | $I_C = 1 \text{ mA}$  | $V_{CEO}$          | 70   |      |      | V    |  |
| Emitter collector voltage  | I <sub>E</sub> = 100 μA   | V <sub>ECO</sub>   | 7    |      |      | V    |  |
| Collector emitter cut-off current  | $V_{CE} = 20 \text{ V}, I_F = 0$                                  | I <sub>CEO</sub>   |      | 10   | 100  | nA   |  |
| COUPLER  |   |                    |      |      |      |      |  |
| Collector emitter saturation voltage   | $I_F = 10 \text{ mA}, I_C = 1 \text{ mA}$                         | V <sub>CEsat</sub> |      |      | 0.3  | V    |  |
| Cut-off frequency  | $V_{CE} = 5 \text{ V}, I_{F} = 10 \text{ mA}, R_{L} = 100 \Omega$ | f <sub>c</sub>     |      | 110  |      | kHz  |  |
| Coupling capacitance   | f = 1 MHz   | C <sub>k</sub>     |      | 0.6  |      | pF   |  |

#### Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

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| CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |          |        |      |      |      |      |  |
|---|---|----------|--------|------|------|------|------|--|
| PARAMETER   | TEST CONDITION                                | PART     | SYMBOL | MIN. | TYP. | MAX. | UNIT |  |
|   |   | VO615A-1 | CTR    | 13   | 30   |      | %    |  |
|   | $V_{CF} = 5 \text{ V}, I_{F} = 1 \text{ mA}$  | VO615A-2 | CTR    | 22   | 45   |      | %    |  |
|   | VCE = 3 V, IF = 1 IIIA                        | VO615A-3 | CTR    | 34   | 70   |      | %    |  |
|   |   | VO615A-4 | CTR    | 56   | 90   |      | %    |  |
|   | V <sub>CE</sub> = 5 V, I <sub>F</sub> = 5 mA  | VO615A   | CTR    | 50   |      | 600  | %    |  |
|   |   | VO615A-5 | CTR    | 50   |      | 150  | %    |  |
| I <sub>C</sub> /I <sub>F</sub>  |   | VO615A-6 | CTR    | 100  |      | 300  | %    |  |
| IC/IF   |   | VO615A-7 | CTR    | 80   |      | 160  | %    |  |
|   |   | VO615A-8 | CTR    | 130  |      | 260  | %    |  |
|   |   | VO615A-9 | CTR    | 200  |      | 400  | %    |  |
|   | V <sub>CE</sub> = 5 V, I <sub>F</sub> = 10 mA | VO615A-1 | CTR    | 40   |      | 80   | %    |  |
|   |   | VO615A-2 | CTR    | 63   |      | 125  | %    |  |
|   |   | VO615A-3 | CTR    | 100  |      | 200  | %    |  |
|   |   | VO615A-4 | CTR    | 160  |      | 320  | %    |  |

| SAFETY AND INSULATION RATED PARAMETERS                  |  |                   |                  |      |      |                   |  |
|---|--|-------------------|------------------|------|------|-------------------|--|
| PARAMETER   | TEST CONDITION   | SYMBOL            | MIN.             | TYP. | MAX. | UNIT              |  |
| Partial discharge test voltage - routine test           | 100 %, t <sub>test</sub> = 1 s   | $V_{pd}$          | 1.6              |      |      | kV                |  |
| Partial discharge test voltage - lot test (sample test) | $t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$ (see figure 2)               | $V_{pd}$          | 1.36             |      |      | kV                |  |
|   | V <sub>IO</sub> = 500 V  | R <sub>IO</sub>   | 10 <sup>12</sup> |      |      | Ω                 |  |
| Insulation resistance                                   | V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C                             | R <sub>IO</sub>   | 10 <sup>11</sup> |      |      | Ω                 |  |
| modation resistance                                     | V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 150 °C<br>(construction test only) | R <sub>IO</sub>   | 10 <sup>9</sup>  |      |      | Ω                 |  |
| Rated impulse voltage                                   |  | V <sub>IOTM</sub> |                  |      | 6000 | V <sub>peak</sub> |  |
| Max. working voltages                                   | Recurring peak voltage   | V <sub>IORM</sub> |                  |      | 850  | V <sub>peak</sub> |  |
| Forward current   |  | I <sub>SI</sub>   |                  |      | 130  | mA                |  |
| Power dissipation                                       |  | P <sub>SO</sub>   |                  |      | 265  | mW                |  |
| Safety temperature                                      |  | T <sub>si</sub>   |                  |      | 150  | °C                |  |
| Creepage distance                                       |  |                   |                  |      | 7.6  | mm                |  |

#### Note

• According to DIN EN 60747-5-5 (VDE 0884), § 7.4.3.8.2 (see figure 2). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.

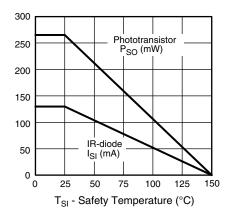


Fig. 2 - Derating Diagram

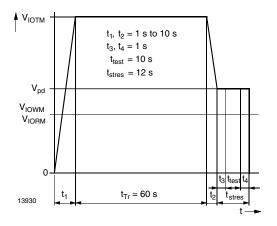


Fig. 3 - Test Pulse Diagram for Sample Test According to DIN EN 60747-5-2 (VDE 0884); IEC 60747-5-5



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| <b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                  |      |      |      |      |  |
|---|---|------------------|------|------|------|------|--|
| PARAMETER   | TEST CONDITION  | SYMBOL           | MIN. | TYP. | MAX. | UNIT |  |
| Delay time  | $V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$         | t <sub>d</sub>   |      | 3    |      | μs   |  |
| Rise time   | $V_{S} = 5 \text{ V}, I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega$   | t <sub>r</sub>   |      | 3    |      | μs   |  |
| Fall time   | $V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$         | t <sub>f</sub>   |      | 4.7  |      | μs   |  |
| Storage time  | $V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$         | t <sub>s</sub>   |      | 0.3  |      | μs   |  |
| Turn-on time  | $V_{S} = 5 \text{ V}, I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega$   | t <sub>on</sub>  |      | 6    |      | μs   |  |
| Turn-off time   | $V_S = 5 \text{ V}, I_C = 2 \text{ mA}, R_L = 100 \Omega$         | t <sub>off</sub> |      | 5    |      | μs   |  |
| Turn-on time  | $V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega$ | t <sub>on</sub>  |      | 3    |      | μs   |  |
| Turn-off time   | $V_S = 5 \text{ V}, I_F = 10 \text{ mA}, R_L = 1 \text{ k}\Omega$ | t <sub>off</sub> |      | 10   |      | μs   |  |

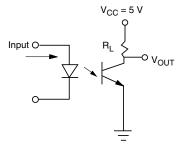


Fig. 4 - Test Circuit

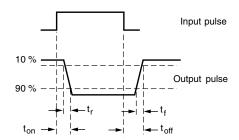


Fig. 5 - Test Circuit and Waveforms

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

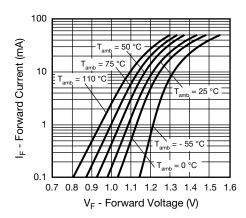


Fig. 6 - Forward Voltage vs. Forward Current

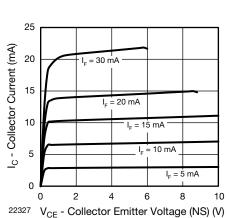


Fig. 7 - Collector Current vs. Collector Emitter Voltage (NS)

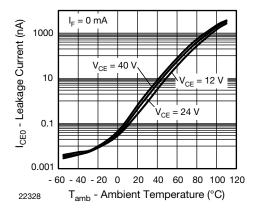


Fig. 8 - Leakage Current vs. Ambient Temperature

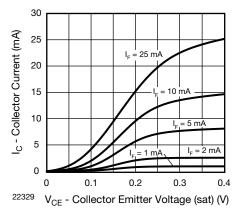


Fig. 9 - Collector Current vs. Collector Emitter Voltage (sat)



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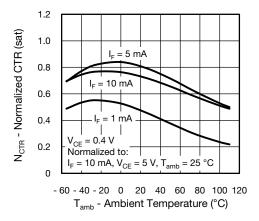


Fig. 10 - Normalized CTR (sat) vs. Ambient Temperature

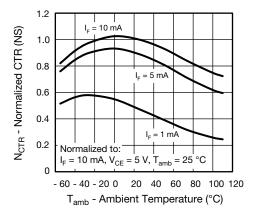


Fig. 11 - Normalized CTR (NS) vs. Ambient Temperature

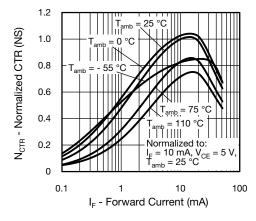


Fig. 12 - Normalized CTR (NS) vs. Forward Current

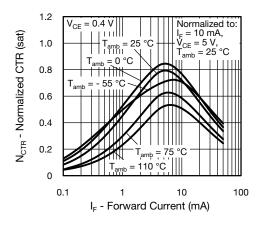


Fig. 13 - Normalized CTR (sat) vs. Forward Current

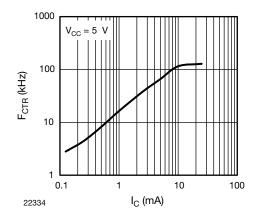


Fig. 14 - F<sub>CTR</sub> vs. I<sub>C</sub> (sat) (mA)

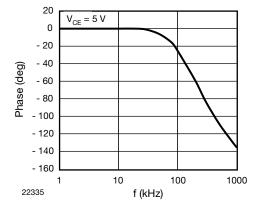


Fig. 15 - F<sub>CTR</sub> vs. Phase Angle (kHz)

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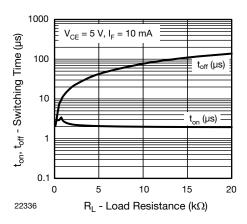
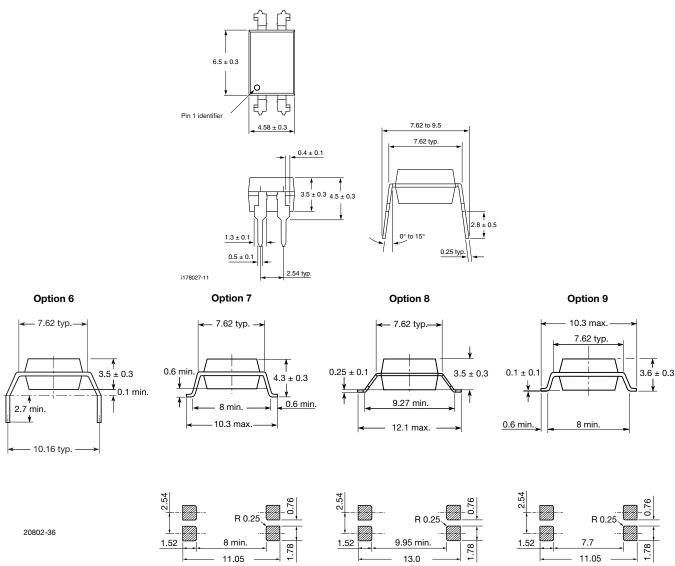


Fig. 16 - Switching Time vs. Load Resistance

### **PACKAGE DIMENSIONS** in millimeters



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### PACKAGE MARKING (Example of VO615A-3X017T)



### **Notes**

- Only options 1, 7, and 8 are reflected in the package marking.
- The VDE logo is only marked on option1 parts.
- Tape and reel suffix (T) is not part of the package marking.

### **PACKING INFORMATION**

| DEVICE PER TUBE              |            |           |           |  |  |  |  |  |
|------------------------------|------------|-----------|-----------|--|--|--|--|--|
| TYPE                         | UNITS/TUBE | TUBES/BOX | UNITS/BOX |  |  |  |  |  |
| DIP-4, standard and option 6 | 100        | 40        | 4000      |  |  |  |  |  |

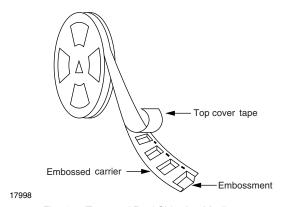


Fig. 17 - Tape and Reel Shipping Medium

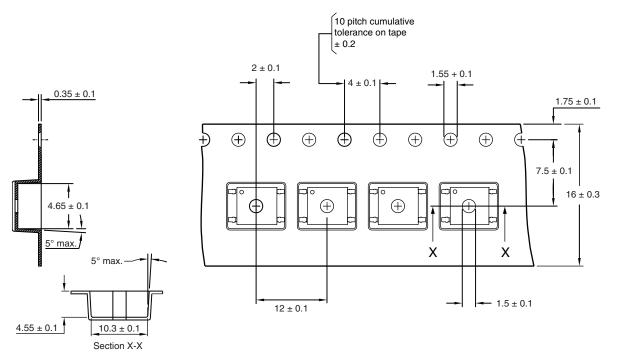


Fig. 18 - Tape and Reel Packing for Option 7 and Option 9 (1000 units per reel)

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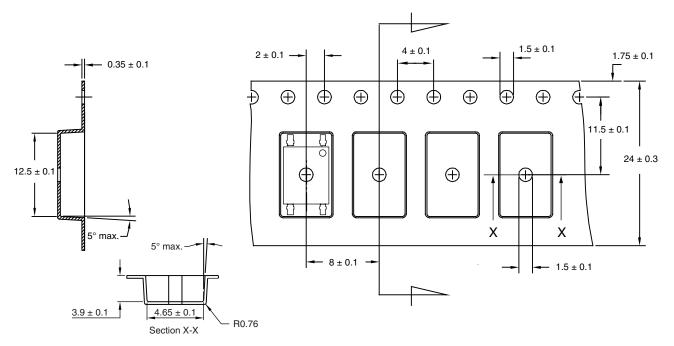


Fig. 19 - Tape and Reel Packing for Option 8 (2000 units per reel)



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# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

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